

Description

This -35A,-30V P-Channel MOSFET in a PDFN 3×3-8L Plastic Package.

Applications

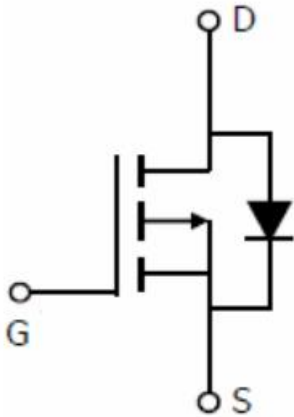
These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

Features

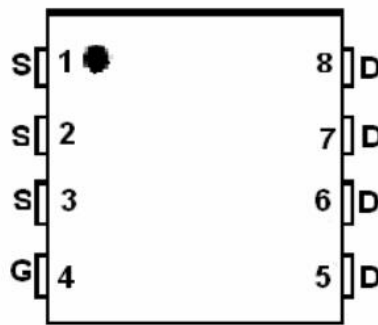
- $V_{DS}$  (V) = -30V
- $I_D$  =-35 A ( $V_{GS} = \pm 20V$ )
- $R_{DS(ON)}@10V \leq 12mR$ (Typ.10.5mR)
- Halogen-Free Product

$V_{DSS}$	$R_{DS(on)}$ Typ	$I_D$
-30V	10.5mΩ	-35A

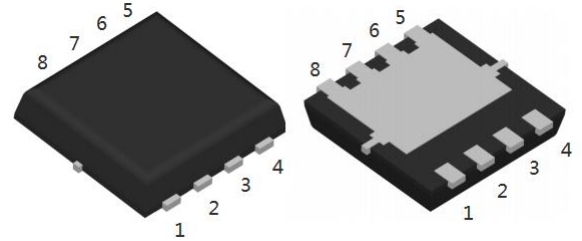
Equivalent Circuit & Pinning



Schematic diagram



Pin assignment



PDFN3X3-8L

**Absolute Maximum Ratings(Ta=25°C)**

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		$V_{DSS}$	-30	V
Drain Current		$I_D(T_C=25^\circ\text{C})$	-35	A
Drain Current - Pulsed		$I_{DM}$	-80	A
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Avalanche Current		$I_{AS}$	17	A
Single Pulsed Avalanche Energy		$E_{AS}$	151	mJ
Power Dissipation		$P_D(T_C=25^\circ\text{C})$	28	W
Operating and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C
Junction-to-Ambient	$t \leq 10$	$R_{\theta JA}$	25	°C/W
Junction-to-Ambient	Steady-State		55	
Junction-to-Case	Steady-State	$R_{\theta JC}$	4.5	

**Electrical Characteristics(Ta=25°C)**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Drain-Source Breakdown Voltage	$BV_{DSS}$	$I_D=-250\mu A$ $V_{GS}=0V$	-30	-36		V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30V$ $V_{GS}=0V$			-1	$\mu A$
Gate-Body leakage current	$I_{GSS}$	$V_{DS}=0V$ $V_{GS}=\pm 20V$			$\pm 100$	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ $I_D=-250\mu A$	-1.0	-1.7	-2.5	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	$V_{GS}=-10V$ $I_D=-20A$		10.5	12	m $\Omega$
		$V_{GS}=-4.5V$ $I_D=-10A$		16.5	18	
Diode Forward Voltage	$V_{SD}$	$I_S=-1A$ $V_{GS}=0V$			-1.2	V
Gate resistance	$R_g$	$V_{GS}=0V$ $V_{DS}=0V$ $f=1MHz$		7.5	10	$\Omega$
Input Capacitance	$C_{iss}$	$V_{GS}=0V$ $V_{DS}=-25V$ $f=1MHz$		2100		pF
Output Capacitance	$C_{oss}$			340		
Reverse Transfer Capacitance	$C_{rss}$			210		
Total Gate Charge	$Q_g(10V)$	$V_{GS}=-10V$ $V_{DS}=-15V$ $I_D=-17A$		35		nC
Total Gate Charge	$Q_g(4.5V)$			17		
Gate-Source Charge	$Q_{gs}$			5.7		
Gate-Drain Charge	$Q_{gd}$			8.8		
Turn-on Delay Time	$t_{d(ON)}$	$V_{GS}=-10V$ $V_{DS}=-15V$ $R_L=0.9\Omega$ $R_{GEN}=3\Omega$		11		ns
Turn-on Rise Time	$t_r$			7.5		
Turn-off Delay Time	$t_{d(OFF)}$			43.5		
Turn-off Fall Time	$t_f$			17.5		

Electrical Characteristic Curve

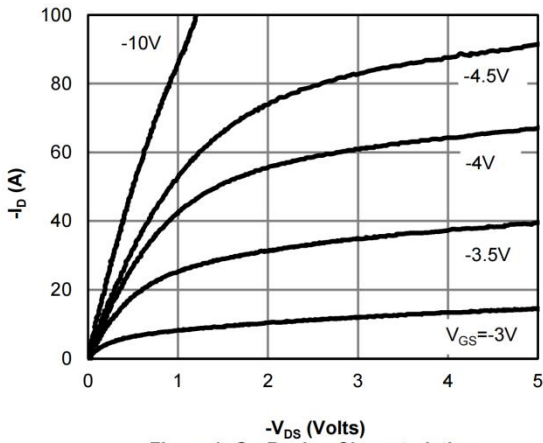


Figure 1: On-Region Characteristics

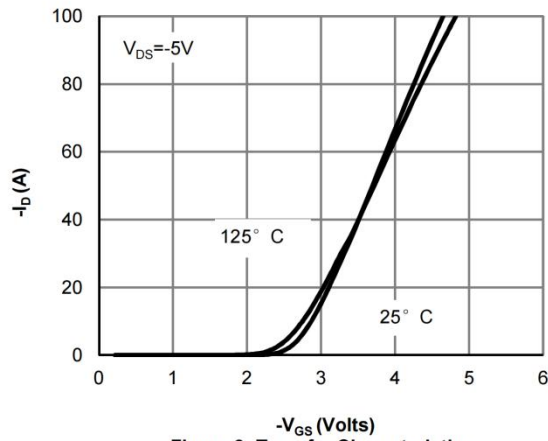


Figure 2: Transfer Characteristics

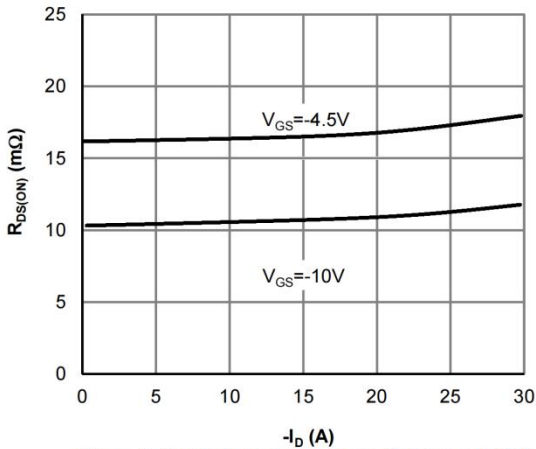


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

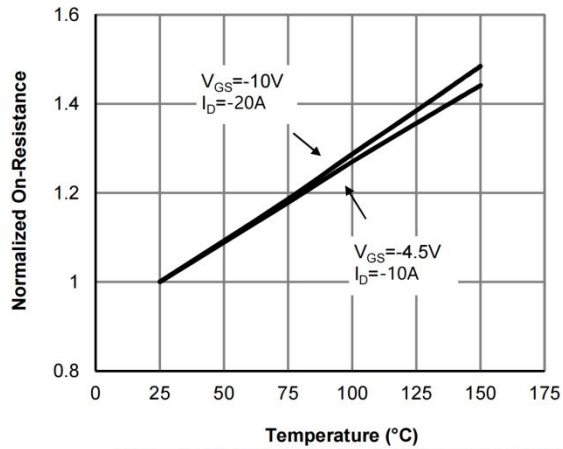


Figure 4: On-Resistance vs. Junction Temperature

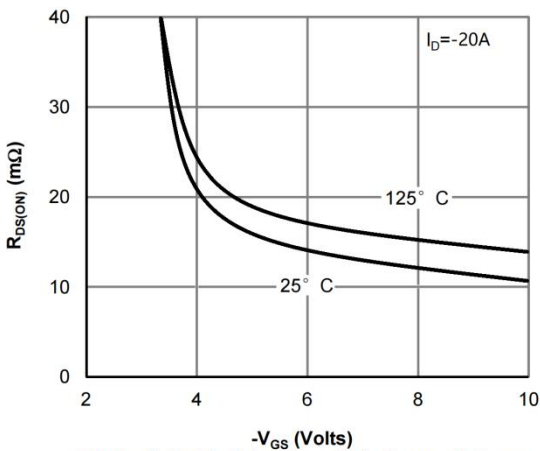


Figure 5: On-Resistance vs. Gate-Source Voltage

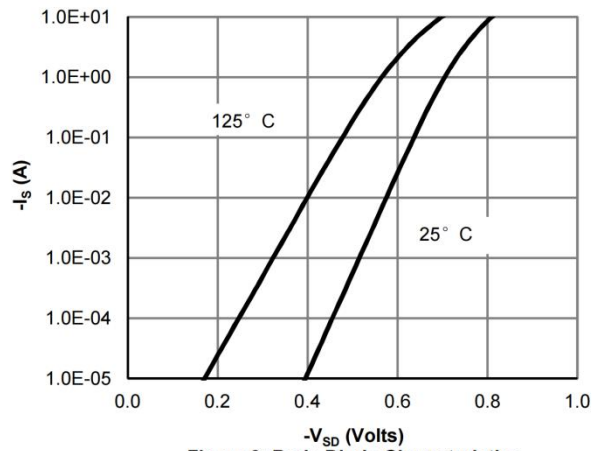


Figure 6: Body-Diode Characteristics

Electrical Characteristic Curve

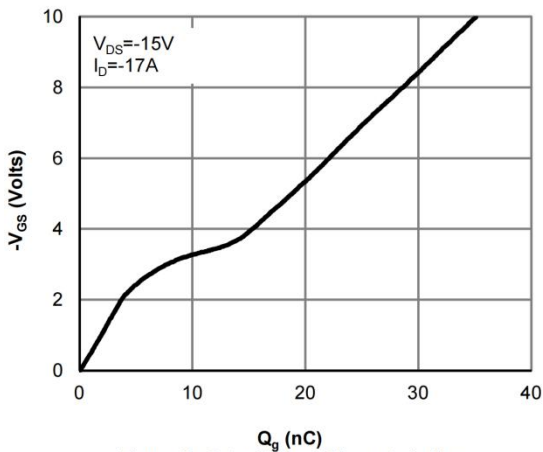


Figure 7: Gate-Charge Characteristics

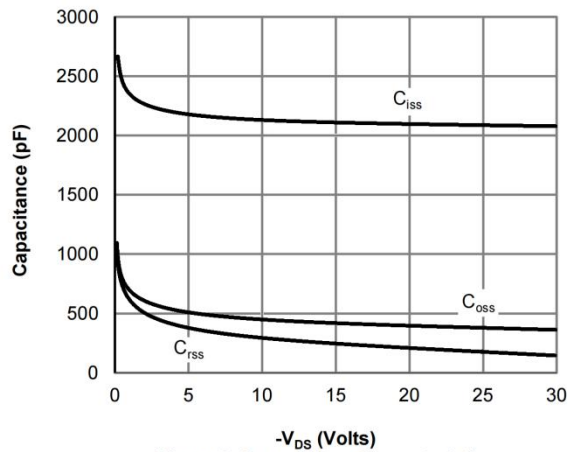


Figure 8: Capacitance Characteristics

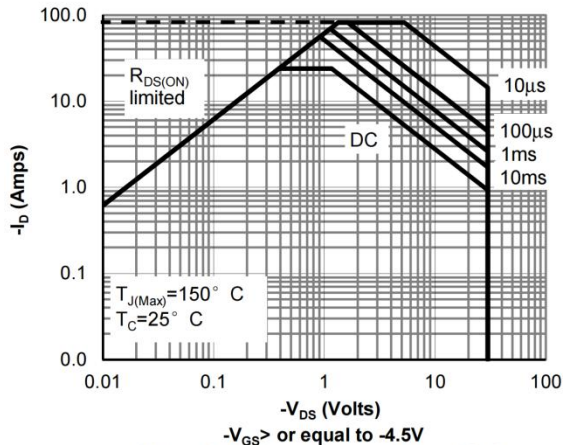


Figure 9: Maximum Forward Biased Safe Operating Area

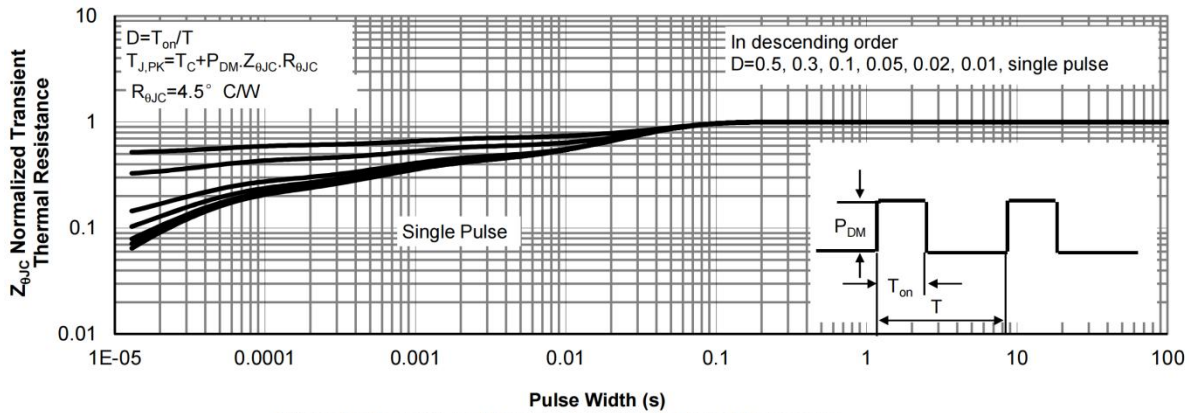
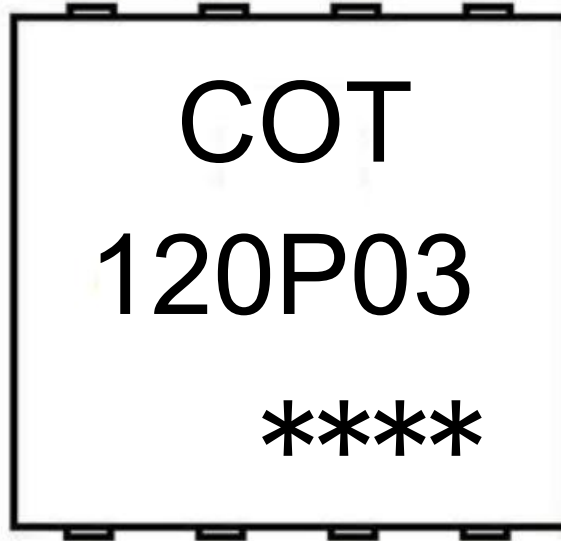


Figure 10: Normalized Maximum Transient Thermal Impedance

Marking Instructions



Note:

COT: Company Logo

120P03: Product Type.

\*\*\*\*: Lot No. Code, code change with Lot No.

Packaging SPEC.

REEL INFORMATION

Package Type	Units					Dimension (unit: mm <sup>3</sup> )		
	Units/Reel	Reels/Inner Box	Units/Inner Box	Inner Boxes/Outer Box	Units/Outer Box	Reel	Inner Box	Outer Box
PDFN3×3-8L	5,000	2	10,000	6	60,000	13" ×12	360×360×50	380×335×366

Package Outline Dimensions

PDFN3X3-8L

Unit:mm

